

Fast switching diode chip in Emitter Controlled 3 -Technology

#### Features:

- 600V Emitter Controlled 3 technology 70 µm chip
- soft, fast switching

**Mechanical Parameters** 

Recommended storage environment

- low reverse recovery charge
- small temperature coefficient

### This chip is used for:

- Power module
- Discrete components



### **Applications:**

- Drives
- White goods
- Resonant applications

Chip Type	<b>V</b> <sub>R</sub>	<b>I</b> F	Die Size	Package
SIDC02D60C8	600V	6A	1.4 x 1.65 mm <sup>2</sup>	sawn on foil

#### Raster size 1.4 x 1.65 $\,\mathrm{mm}^2$ Area total 2.31 Anode pad size 0.97 x 1.22 **Thickness** 70 μm Wafer size 200 mm 12228 Max. possible chips per wafer Passivation frontside Photoimide 3200 nm AlSiCu Pad metal Ni Ag -system Backside metal suitable for epoxy and soft solder die bonding Die bond Electrically conductive glue or solder Wire bond Al, ≤500µm Reject ink dot size Ø 0.65mm; max 1.2mm

Store in original container, in dry nitrogen, in dark

environment, < 6 month at an ambient temperature of 23°C



### **Maximum Ratings**

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	$V_{RRM}$	<i>T</i> <sub>vj</sub> = 25 ℃	600	V
Continuous forward current	I <sub>F</sub>	<i>T</i> <sub>vj</sub> < 150℃	1)	Α
Maximum repetitive forward current	I <sub>FRM</sub>	<i>T</i> <sub>vj</sub> < 150℃	12	
Junction temperature range	$T_{\rm vj}$		-40+175	°C
Operating junction temperature	$T_{\rm vj}$		-40+150	°C
Dynamic ruggedness <sup>2)</sup>	$P_{max}$	$I_{\text{Fmax}} = 12\text{A}, \ V_{\text{Rmax}} = 600\text{V}, \ T_{\text{vj}} \le 150^{\circ}\text{C}$	tbd	kW

<sup>1)</sup> depending on thermal properties of assembly

### Static Characteristics (tested on wafer), $T_{vj} = 25 \text{ }^{\circ}\text{C}$

Parameter	Symbol	Conditions	Value			Unit
raiailletei	Symbol		min.	typ.	max.	Oill
Reverse leakage current	$I_{R}$	V <sub>R</sub> =600V			27	μA
Cathode-Anode breakdown Voltage	$V_{BR}$	I <sub>R</sub> =0.25mA	600			V
Diode forward voltage	$V_{F}$	I <sub>F</sub> =6A	1.25	1.6	1.95	V

### **Further Electrical Characteristics**

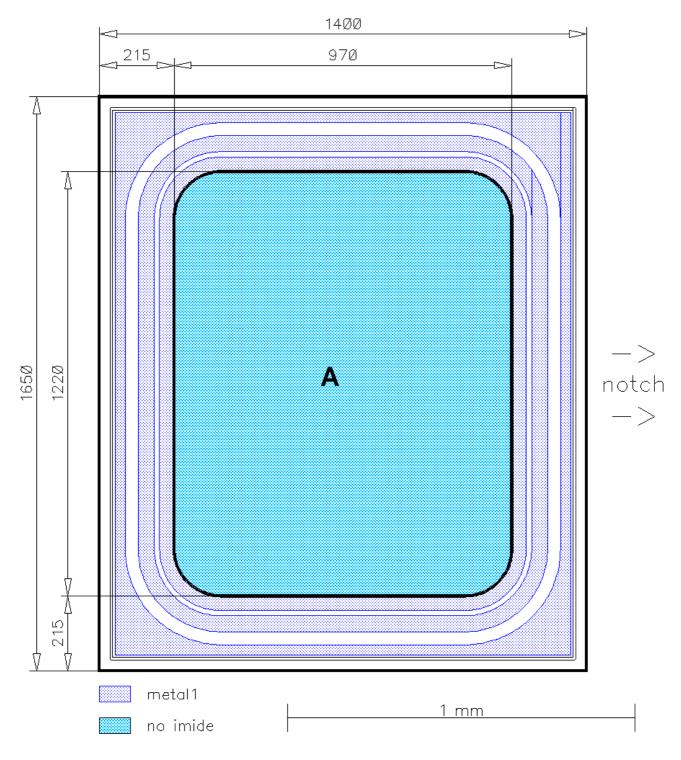
Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

<sup>&</sup>lt;sup>2)</sup> not subject to production test - verified by design/characterisation



### **Chip Drawing**

Die-Size 1400 um x 1650 um



### A: Anode pad

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Description
AQL 0,65 for visual inspection according to failure catalogue
Electrostatic Discharge Sensitive Device according to MIL-STD 883

### **Revision History**

Version	Subjects (major changes since last revision)	Date

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